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Supporting Information

Transition-Metal Embedded gt-C₃N₃ Monolayers: High-Temperature Ferromagnetism

and High Anisotropy

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Figure S2: Optimized structures (top and side views) of $TM@gt-C_3N_3$ (TM = Sc to Cu) structures.

Table S1: Bond lengths and net effective charges calculated from Bader Charge analysis of	
gt-C ₃ N ₃ and TM@gt-C ₃ N ₃ (See Figure 1 in the manuscript for atom numbering)	

Compound	Bond length (Å)		Net Effective Charge		
			С	Ν	ТМ
gt-C ₃ N ₃	C2-N	V1 = 1.33	C1 = +0.98	N1=-1.26	
0 1 1	C2-N	J2 = 1.39	C2 = +1.57	N2=-1.01	
	C1-N	M1 = 1.27			
	C1-N	J2 = 1.41			
Sc@gt-C ₃ N ₃	Sc-N= 2.12	C2-N2 = 1.44	C1 = +0.55	N1=-1.31	Sc = +1.44
	Sc-C=2.15	C2-N1 = 1.35	C2 = +1.36	N2 = -1.12	
		C1-N1 = 1.36			
		C1-N2 = 1.43			
Ti@gt-C ₃ N ₃	Ti-N= 2.05	C2-N2 = 1.42	C1 = +0.48	N1=-1.30	Ti = +1.33
	Ti-C= 2.06	C2-N1 = 1.35	C2 = +1.39	N2 = -1.11	
		C1-N1 = 1.36			
		C1-N2 = 1.41			
V@gt-C ₃ N ₃	V-N= 2.01	C2-N2 = 1.43	C1 = +0.53	N1=-1.29	V = +1.24
	V-C= 1.99	C2-N1 = 1.35	C2 = +1.39	N2 = -1.11	
		C1-N1 = 1.36			
		C1-N2 = 1.42			
Cr@gt-C ₃ N ₃	Cr-N= 1.97	C2-N2 = 1.44	C1 = +0.06	N1=-1.32	Cr = +1.62
	Cr-C=1.94	C2-N1 = 1.35	C2 = +1.97	N2 = -1.07	
		C1-N1 = 1.34			
		C1-N2 = 1.42			
Mn@gt-C ₃ N ₃	Mn-N= 1.94	C2-N2 = 1.43	C1 = +0.06	N1 = -1.32	Mn = +1.68
	Mn-C=1.90	C2-N1 = 1.36	C2 = +1.99	N2= -1.15	
		C1-N1 = 1.35			
		C1-N2 = 1.42			
Fe@gt-C ₃ N ₃	Fe-N= 1.92	C2-N2 = 1.41	C1 = +0.07	N1=-1.27	Fe = +1.57
	Fe-C=1.84	C2-N1 = 1.36	C2 = +2.00	N2=-1.17	
		C1-N1 = 1.36			
		C1-N2 = 1.42			
Co@gt-C ₃ N ₃	Co-N= 1.90	C2-N2 = 1.39	C1 = +0.72	N1=-1.23	Co = +0.66
	Co-C= 1.79	C2-N1 = 1.35	C2 = +1.50	N2= -1.19	
		C1-N1 = 1.35			
		C1-N2 = 1.42			
Ni@gt-C ₃ N ₃	Ni-N= 1.89	C2-N2 = 1.39	C1 = +0.79	N1=-1.25	Ni = +0.62
	Ni-C=1.83	C2-N1 = 1.35	C2 = +1.51	N2 = -1.21	
		C1-N1 = 1.34			
		C1-N2 = 1.40			
Cu@gt-C ₃ N ₃	Cr-N= 1.93	C2-N2 = 1.41	C1 = +0.78	N1=-1.27	Cu=+0.72
	Cr-C=1.89	C2-N1 = 1.35	C2 = +1.46	N2 = -1.20	

C1 $N1 = 1.22$
C1-N1 = 1.33
C1-N2 = 1.40
$C1^{-1}N^{2}$ 1.70

Text S1. Formation Energy (E_f), Binding Energy (E_B) and Cohesive Energy (E_{coh}) Calculations:

The N-vacancy formation energy is calculated for $g-C_3N_3$ system with the help of the following equation.

$$E_{N-vacancy} = [E_{gt-C3N4} - (E_{gt-C3N3} + \mu_N)]$$
(1)

Here, $E_{TM@g-C3N4}$ is the total energy of TM@gt-C₃N₄, E_{g-C3N3} is the total energy of gt-C₃N₃ sheet, and μ_N represents the chemical potential of nitrogen (N). μ_N is calculated from the total energy of an isolated N₂ molecule.

The formation energy (E_f) is calculated for each TM embedding in the pore of gt-C₃N₃ (Figure 1) using the following equation:

$$E_{f} = [E_{TM@g-C3N3} - (E_{gt-C3N3} + \mu_{TM})]$$
(2)

where $E_{TM@g-C3N3}$ is the total energy of TM@gt-C₃N₃, E_{g-C3N3} is the total energy of gt-C₃N₃ sheet, and μ_{TM} represents the chemical potential of TM in their respective bulk structure. The chemical potentials of Cr (μ_{Cr}), Mn (μ_{Mn}), and Fe (μ_{Fe}) are calculated from their most stable crystals such as Cr in bcc,¹ Mn in cubic,² and Fe in bcc,³ respectively.

We have also calculated the binding energy (E_B) of TM in the pore of g-C₃N₃ using the following equation:

$$E_{\rm B} = E_{\rm gt-C3N3+TM} - (E_{\rm gt-C3N3} + E_{\rm TM})$$
(3)

where, E_{TM} represents the total energy of the isolated atom.

The cohesive energy of a solid is the energy required to dissociate the solid into their isolated atomic species. It is calculated by using the following equation:

$$E_{coh} = E_{Solid} - \sum_{A} E_{A}^{isolated}$$
(4)



Figure S3: Total electron density (Isosurface value: 0.18 e.Å^{-3}) and electrostatic potentials (ESP) plots (Isosurface value: 0.03 e.Å^{-3}) of TM@gt-C₃N₃ (Sc to Cu). The blue and red colours denote less and more electron dense area in the electrostatic potential surface.

Systems (TM@gt-C ₃ N ₃)	E _B /TM (eV)	E _F (eV)	E _{Coh} (eV)	Imaginary Frequency (<i>i</i>)	
				THz	cm ⁻¹
Sc	-3.81	3.22	-4.11	1.61	53.76
Ti	-3.72	4.08	-5.02	1.73	57.80
V	-5.95	2.60	-5.56	0.79	26.31
Cr	-9.50	-1.81	-4.27	0.005	0.16
Mn	-8.26	-1.32	-3.12	0.012	0.42
Fe	-8.10	-1.17	-4.46	0.013	0.45
Со	-6.81	0.94	-4.62	1.36	45.45
Ni	-5.22	1.07	-4.67	0.96	32.07
Cu	-3.73	1.04	-3.75	0.50	16.69

Table S2: Binding energy (E_B/TM), formation energy (E_F), cohesive energy of TM bulk ($E_{Coh}/atom$) and phonon frequency of TM@gt-C₃N₃ systems. (TM = Sc to Cu)



Figure S4: Phonon band structures of $TM@gt-C_3N_3$ (TM = Sc to Cu)



Figure S5: Total energy fluctuation during AIMD simulations of $Cr@gt-C_3N_3$, $Mn@gt-C_3N_3$ and $Fe@gt-C_3N_3$ systems at 400 and 500 K. The structures represent the snapshot at 10 ps for each simulation.



Figure S6: Strain energy of (a) $Cr@gt-C_3N_3$ (b) $Mn@gt-C_3N_3$ and (c) $Fe@gt-C_3N_3$ under inplane uniaxial and equi-biaxial strains.

Table S3: Calculated Young's Modulus and Poisson's ratio of $TM@gt-C_3N_3$ by applyinguniaxial and equi-biaxial strain.

Compound	Young's Modulus	Poisson's Ratio	Elastic constants
	(GPa)		(GPa)
Cr@gt-C ₃ N ₃	124.97	0.49	$C_{11} = 166.32 C_{12} = 82.92 C_{44} = 41.70$
Mn@gt-C ₃ N ₃	113.26	0.50	$C_{11} = 153.12 C_{12} = 78.12 C_{44} = 37.50$
Fe@gt-C ₃ N ₃	114.98	0.49	$C_{11} = 153.01 C_{12} = 76.28 C_{44} = 38.20$



Figure S7. d-orbital splitting energy diagram for Cr, Mn and Fe@gt-C₃N₃ systems.



Figure S8: (a) TDOS and pDOS plot of (a) $Cr@gt-C_3N_3$, (b) $Mn@gt-C_3N_3$ and (c) $Fe@gt-C_3N_3$ (Fermi level is shifted to zero and indicated by a black dashed line).

Table S4: Exchange energy (E_{ex}) and Curie temperature value of TM@gt-C₃N₃ system.

	Magnetic	Exchange energy	Energy Difference	Curie	MAE in
Compound	Moment/TM	(meV)/TM	(meV)/TM	Temperature	(meV)/TM
	(µ _B)	$[\mathbf{E}_{ex} = \mathbf{E}_{FM} - \mathbf{E}_{AFM}]$	$(\mathbf{E}_{diff} = \mathbf{E}_{FM} - \mathbf{E}_{NSP})$	(T _C) in (K)	(Magnetic
					Anisotropy
					Energy)
Cr@gt-C ₃ N ₃	3.69	-312.99	-53.79	338* (205) ⁴ (252) ⁵	$4.02^{\#}$ (2.40) ⁶ (2.23) ⁷
Mn@gt-C ₃ N ₃	4.75	-307.74	-46.13	328	2.44
Fe@gt-C ₃ N ₃	3.85	-303.55	-75.21	326	1.19

*Cr@gt-C₃N₃ shows higher Curie tempareture compare to first row transition metal incorporated carbon nitride systems such as V-g-C₃N₄ ⁴ and Cu-gt-C₃N₄.⁵ In fact, Cr@gt-C₃N_{3 has} higher MAE compared to the previously reported Fe embedded graphyne⁶ and Co nanowaires systems.⁷ The previous studies on carbon nitride based systems did not report MAE and thus we could not comapare with carbon nitride based systems.







Figure S10. Band structures of Fe@gt-C₃N₃ by applying 1%, 5% and 10% (a) uniaxial and (b) biaxial tensile strain. The Fermi level is set to zero and indicated by blue dashed line

Text S2. Calculation of Magnetic Anisotropy Energy (MAE)

The magnetic anisotropy energy (MAE) is calculated by applying the torque approach.⁸⁻⁹ Non-collinear self-consistent calculations (including spin orbit coupling) are performed in the z, y and x axis magnetization directions, respectively. MAE originates from the perpendicular and in plane contribution of spin orbit coupling (SOC), which can be expressed in terms of angular momentum operators L_x , L_y or L_z . So the contribution of different spins (up ' $\uparrow\uparrow$ ' and down ' $\downarrow\downarrow$ ') can be expressed by the second order perturbation equation.¹⁰

$$MAE = \xi^{2} \sum_{o,u} \frac{|\langle o | L_{Z} | u \rangle |^{2} - |\langle o | L_{X} | u \rangle |^{2}}{E_{u} - E_{o}}$$

Here, o and u represent the occupied and unoccupied electronic states, respectively. The E_o and E_u in the denominator are their respective band energies. L_Z and L_X are the angular momentum operators along Z and X axis, and ξ denotes the strength of the SOC. So, a

potential with good MAE for practical application should hold a high value of ξ . Then, the MAE is calculated using the following equation:

$$MAE = E_{S0} - E_{S1}$$
 (5)

Where E_{S0} is the energy of the materials without employing any magnetic axis and E_{S1} is the energy in presence of an easy axis. Total energies are converged to a precision of 10⁻⁶ eV in MAE calculations.

Text S3.1 Mean Field Theory (MFT):

We have taken the MFT approach to calculate the Curie tempareture for the two dimentional TM@gt-C₃N₄ systems. This method has been previously used by Li et al.¹¹ for the Curie tempareture calculation for Mn-phthalocyanine (MnPc) system. The main idea behind MFT method is to replace all interactions to any one body with an average or effective interaction.⁸ It reduces any multi-body problem into an effective one-body problem. The detailed partition function can be written as follows,

$$\sum_{Z = m = -M, -M + 2, \dots, M - 2, M} e^{\gamma J m < M > /k_B T}$$
(6)

Here, 'J \Box ' is the exchange parameter, ' γ ' is the coordination number, 'm' is the ensembleaverage magnetic moment, and 'M' is the calculated magnetic moment of TM.

Thus, the average spin of each magnet becomes,

$$= \frac{1}{Z} \sum_{m=-M, -M+2,...,M-2,M} m \times e^{\gamma J m < M > /k_B T}$$
(7)

Now, if we assume that, $P = \frac{\gamma J}{k_B T}$, then the equation 5 becomes,

The above equation can be easily deducible when the parameter 'P' varies along with the static solution <m>. At the critical point,

$$P = P_c = \frac{\gamma J'}{k_B T_c}$$
(8)

At this critical point, the phase transition of the system between ferromagnetic to paramagnetic occurs. This critical point is known as Curie temperature.

3.2 Monte Carlo Simulations:

Monte Carlo simulations involve generating a subset of configurations or samples, chosen using a random algorithm from a configuration space, according to a probability distribution or weight function. Observables are then computed as averages over the samples.¹²

One sample or configuration of the magnet is a particular assignment of spin values, say

$$s_1 = +1; s_2 = -1; s_3 = +1; \dots, s_{N_S} = +1$$
 (9)

in which each spin is set "up" or "down". According to statistical mechanics, the average value of an observable is got by weighting each configuration with the Boltzmann factor. For example, the average magnetization at some fixed temperature T is given by,

$$= \frac{\sum_{Config} Me^{-E/k_B T}}{\sum_{Config} e^{-E/k_B T}}$$
(10)

At the Curie temperature (T_c) we expect a marked fluctuation in the magnetic moment (M).

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